CENG 4480 Embedded System Development & Applications

Lecture 09: Memory 1

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- (Latest update: October 27, 2021)

Fall 2021



1 Introduction

- **2** Memory Principle
- 3 Random Access Memory (RAM)
- 4 Non-Volatile Memory

5 Conclusion

Overview



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- 3 Random Access Memory (RAM)
- 4 Non-Volatile Memory

5 Conclusion

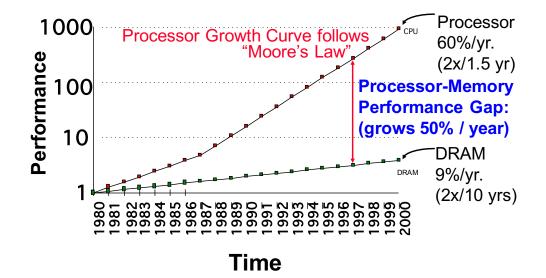
Combinational Circuit:

- Always gives the same output for a given set of inputs
- E.g., adders

Sequential Circuit:

- Store information
- Output depends on stored information
- E.g., counter
- Need a storage element





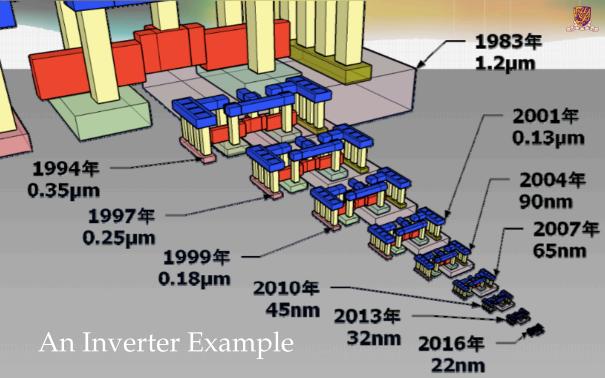
Processor-DRAM Memory Performance Gap

Moore's Law

Transistor number on a unit area would double every 1.5 years.

*1965 paper reprint: link







2005







Memory Card Scaling



• Maximum size of memory is determined by addressing scheme

E.g.

16-bit addresses can only address $2^{16} = 65536$ memory locations

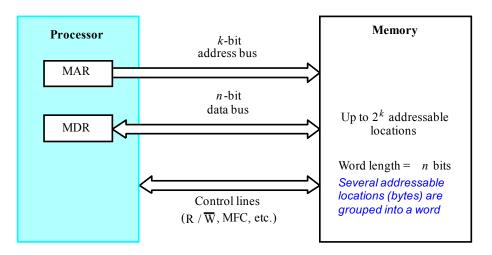
- Most machines are byte-addressable
- each memory address location refers to a byte
- Most machines retrieve/store data in words
- Common abbreviations
 - $1k \approx 2^{10}$ (kilo)
 - $1M \approx 2^{20}$ (Mega)
 - $1G \approx 2^{30}$ (Giga)
 - $1T \approx 2^{40}$ (Tera)

Simplified View



Data transfer takes place through

- MAR: memory address register
- MDR: memory data register





Processor usually runs much faster than main memory:

- Small memories are fast, large memories are slow.
- Use a cache memory to store data in the processor that is likely to be used.

Main memory is limited:

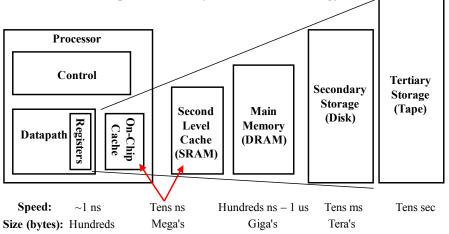
- Use virtual memory to increase the apparent size of physical memory by moving unused sections of memory to disk (automatically).
- A translation between virtual and physical addresses is done by a memory management unit (MMU)
- To be discussed in later lectures

Memory Hierarchy



Taking advantage of the **principle of locality**:

- Present the user with as much memory as is available in the cheapest technology.
- Provide access at the speed offered by the fastest technology





Memory Access Time

time between start and finish of a memory request

Memory Cycle Time

minimum delay between successive memory operations

Random Access Memory (RAM)

Property: comparable access time for any memory locations



1 Introduction

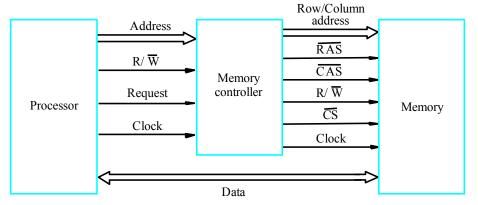
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- A memory controller is normally used to interface between the memory and the processor.
- DRAMs have a slightly more complex interface as they need refreshing and they usually have time-multiplex signals to reduce pin number.
- SRAM interfaces are simpler and may not need a memory controller.



RAS (CAS) = Row (Column) Address Strobe; CS = Chip Select



- The memory controller accepts a complete address and the R/W signal from the processor.
- The controller generates the RAS (Row Access Strobe) and CAS (Column Access Strobe) signals.

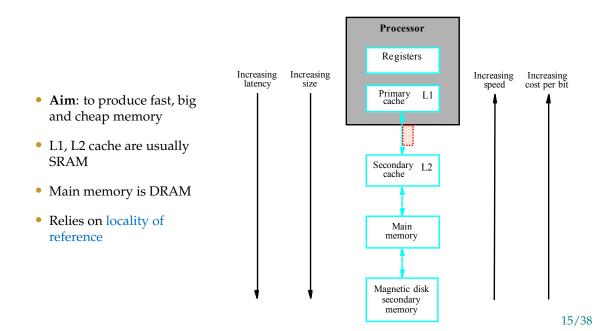


- The memory controller accepts a complete address and the R/W signal from the processor.
- The controller generates the RAS (Row Access Strobe) and CAS (Column Access Strobe) signals.
- The high-order address bits, which select a row in the cell array, are provided first under the control of the RAS (Row Access Strobe) signal.
- Then the low-order address bits, which select a column, are provided on the same address pins under the control of the CAS (Column Access Strobe) signal.



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- Then the low-order address bits, which select a column, are provided on the same address pins under the control of the CAS (Column Access Strobe) signal.
- The right memory module will be selected based on the address. Data lines are connected directly between the processor and the memory.
- SDRAM needs refresh, but the refresh overhead is only less than 1 percent of the total time available to access the memory.







Temporal Locality (locality in time)

- If an item is referenced, it will tend to be referenced again soon.
- When information item (instruction or data) is first needed, brought it into cache where it will hopefully be used again.

Spatial Locality (locality in space)

- If an item is referenced, neighbouring items whose addresses are close-by will tend to be referenced soon.
- Rather than a single word, fetch data from adjacent addresses as well.



By taking advantages of the principle of locality:

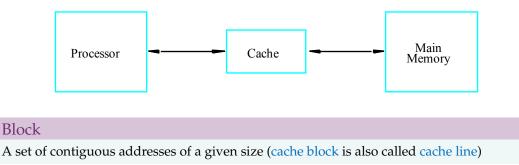
- Present the user with as much memory as is available in the cheapest technology.
- Provide access at the speed offered by the fastest technology.

DRAM is slow but cheap and dense:

- Good choice for presenting the user with a BIG memory system main memory SRAM is fast but expensive and not very dense:
 - Good choice for providing the user FAST access time L1 and L2 cache



- Need to determine how the cache is organized
- Mapping functions determine how memory addresses are assigned to cache locations
- Need to have a replacement algorithm to decide what to do when cache is full (i.e. decide which item to be unloaded from cache).





- Contents of a block are read into the cache the first time from the memory.
- Subsequent accesses are (hopefully) from the cache, called a cache read hit.
- Number of cache entries is relatively small, need to keep most likely used data in cache.
- When an un-cached block is required, need to employ a replacement algorithm to remove an old block and to create space for the new one.



Scheme 1: Write-Through

Cache and main memory updated at the same time.

Note that read misses and read hits can occur.



Scheme 1: Write-Through

Cache and main memory updated at the same time.

Note that read misses and read hits can occur.

Scheme 2: Write-Back

Update cache only and mark the entry dirty. Main memory will be updated later when cache block is removed.

Note that write misses and write hits can occur.



Question 2:

Which write scheme is simpler? Which one has better performance? Why?



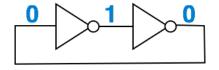
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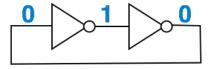


• What if we add feedback to a pair of inverters?

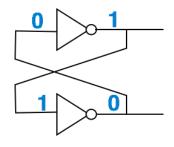




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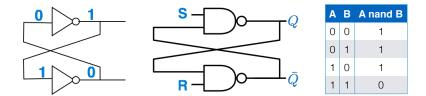


- Usually drawn as a ring of cross-coupled inverters
- Stable way to store one bit of information (w. power)





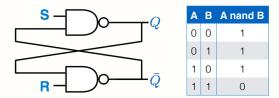
- Replace inverter with NAND gate
- RS Latch



QUESTION:



What's the Q value based on different R, S inputs?



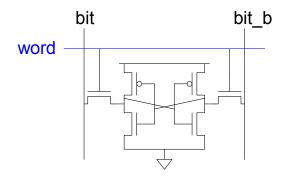
• R=S=1:

- S=0, R=1:
- S=1, R=0:
- R=S=0:

SRAM Cell

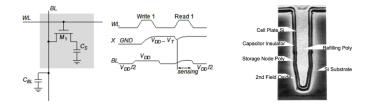


- At least 6 transistors (6T)
- Used in most commercial chips
- A pair of weak cross-coupled inverters
- Data stored in cross-coupled inverters





- 1 Transistor (1T)
- Requires presence of an extra capacitor
- Modifications in the manufacturing process.
- Higher density
- Write: Charged or discharged the capacitor (slow)
- **Read**: Charge redistribution takes place between bit line and storage capacitance





Static RAM (SRAM)

- Capable of retaining the state as long as power is applied.
- They are fast, low power (current flows only when accessing the cells) but costly (require several transistors), so the capacity is small.
- They are the Level 1 cache and Level 2 cache inside a processor, of size 3 MB or more.

Dynamic RAM (DRAM)

- store data as electric charge on a capacitor.
- Charge leaks away with time, so DRAMs must be refreshed.
- In return for this trouble, much higher density (simpler cells).

- The common type used today as it uses a clock to synchronize the operation.
- The refresh operation becomes transparent to the users.
- All control signals needed are generated inside the chip.
- The initial commercial SDRAM in the1990s were designed for clock speed of up to 133MHz.
- Today's SDRAM chips operate with clock speeds exceeding 1 GHz.



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Memory modules are used to hold several SDRAM chips and are the standard type used in a computer's motherboard, of size like 4GB or more.

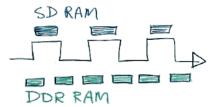






- normal SDRAMs only operate once per clock cycle
- Double Data Rate (DDR) SDRAM transfers data on both clock edges
- DDR-2 (4x basic memory clock) and DDR-3 (8x basic memory clock) are in the market.
- They offer increased storage capacity, lower power and faster clock speeds.
- For example, DDR2 can operate at clock frequencies of 400 and 800 MHz. Therefore, they can transfer data at effective clock speed of 800 and 1600 MHz.





1 Hertz

1 Cycle per second

RAM Туре	Theoretical Maximum Bandwidth		
SDRAM 100 MHz (PC100)	100 MHz X 64 bit/ cycle = 800 MByte/sec		
SDRAM 133 MHz (PC133)	133 MHz X 64 bit/ cycle = 1064 MByte/sec		
DDR SDRAM 200 MHz (PC1600)	2 X 100 MHz X 64 bit/ cycle ~= 1600 MByte/sec		
DDR SDRAM 266 MHz (PC2100)	2 X 133 MHz X 64 bit/ cycle ~= 2100 MByte/sec		
DDR SDRAM 333 MHz (PC2600)	2 X 166 MHz X 64 bit/ cycle ~= 2600 MByte/sec		
DDR-2 SDRAM 667 MHz (PC2-5400)	2 X 2 X 166 MHz X 64 bit/ cycle ~= 5400 MByte/sec		
DDR-2 SDRAM 800 MHz (PC2-6400)	2 X 2 X 200 MHz X 64 bit/ cycle ~= 6400 MByte/sec		

Bandwidth comparison. However, due to latencies, SDRAM does not perform as good as the figures shown.



Example

- Mary acts FAST but she's always LATE.
- Peter is always **PUNCTUAL** but he is **SLOW**.



Example

- Mary acts FAST but she's always LATE.
- Peter is always **PUNCTUAL** but he is **SLOW**.

Bandwidth:

• talking about the "number of bits/bytes per second" when transferring a block of data steadily.

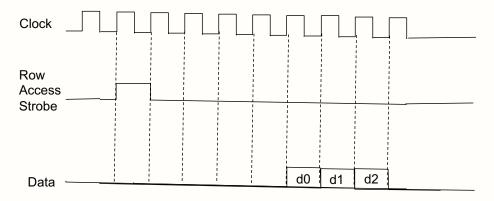
Latency:

- amount of time to transfer the first word of a block after issuing the access signal.
- Usually measure in "number of clock cycles" or in $ns/\mu s$.



Question:

Suppose the clock rate is 500 MHz. What is the latency and what is the bandwidth, assuming that each data is 64 bits?





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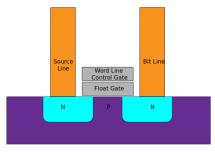


- Memory content fixed and cannot be changed easily.
- Useful to bootstrap a computer since RAM is volatile (i.e. lost memory) when power removed.
- We need to store a small program in such a memory, to be used to start the process of loading the OS from a hard disk into the main memory.

PROM/EPROM/EEPROM

FLASH Memory

- Flash devices have greater density, higher capacity and lower cost per bit.
- Can be read and written
- This is normally used for non-volatile storage
- Typical applications include cell phones, digital cameras, MP3 players, etc.







- Flash cards are made from FLASH chips
- Flash cards with standard interface are usable in a variety of products.
- Flash cards with USB interface are widely used memory keys.
- Larger cards may hold 32GB. A minute of music can be stored in about 1MB of memory, hence 32GB can hold 500 hours of music.







- Flash is just one type of EEPROM.
- Flash uses NAND-type memory, while EEPROM uses NOR type.
- Flash is **block**-wise erasable, while EEPROM is **byte**-wise erasable.
- Flash is constantly rewritten, while other EEPROMs are seldom rewritten.
- Flash is used when large amounts are needed, while EEPROM is used when only small amounts are needed.



	ATMega168	ATMega328P	ATmega1280	ATmega2560
Flash (1 kByte used for bootloader)	16 kBytes	32 kBytes	128 kBytes	256 kBytes
SRAM	1024 bytes	2048 bytes	8 kBytes	8 kBytes
EEPROM	512 bytes	1024 bytes	4 kBytes	4 kBytes



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- Processor usually runs much faster than main memory
- Common RAM types: SRAM, DRAM, SDRAM, DDR SDRAM
- Principle of locality: Temporal and Spatial
 - Present the user with as much memory as is available in the cheapest technology.
 - Provide access at the speed offered by the fastest technology.
- Memory hierarchy:
 - Register \rightarrow Cache \rightarrow Main Memory \rightarrow Disk \rightarrow Tape